TENTATIVE

TOSHIBA Photocoupler GaAlAs Ired + Photo IC

TLP759(IGM)

Transistor Invertor
Inverter For Air Conditioner
Line Receiver
IPM Interfaces

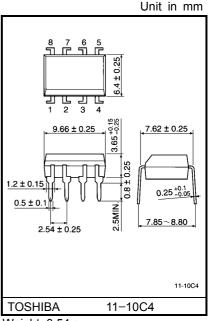
The TOSHIBA TLP759(IGM) consists of a GaAlAs high-output light emitting diode and a high speed detector of one chip photo diodetransistor.

This unit is 8-lead DIP.

TLP759(IGM) has no internal base connection, and a faraday shield integrated on the photodetector chip provides an effective common mode noise transient immunity.

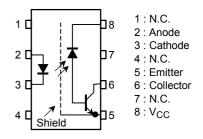
TLP759(IGM) guarantees minimum and maximum of propagation delay time, switching time dispersion, and high common mode transient immunity. Therefor TLP759(IGM) is suitable for isolation interface between IPM(intelligent power module) and control IC circuits in motor control application.

- Isolation voltage: 5000V_{rms} (min.)
- Common mode transient immunity
 - $\pm 10 \text{kV} / \mu \text{s} \text{ (min.)}$ @VCM = 1500 V
 - Switching Time
- : t_{pHL} , $t_{pLH} = 0.1 \mu s$ (min.)
 - = 0.0-- (-----)
 - $= 0.8 \mu s \text{ (max.)}$
 - @I_F = 10mA,V_{CC} = 15V,R_L = 20kΩ,Ta = 25°C
- Switching time dispersion: 0.7μs (max.) (|tpLH-tpHL|)
- TTL compatible
- UL recognized: UL1577, file no.E67349

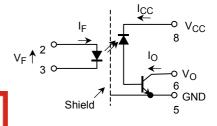


Weight: 0.54 g

Pin Configuration(top view)



Schematic



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Option (D4) type

VDE approved: DIN VDE0884 / 06.92,

Maximum operating insulation voltage: $890 V_{PK}$ Highest permissible over voltage: $6000 V_{PK}$

(Note 1) When a VDE0884 approved type is needed, please designate the "Option (D4)"

• Structural parameter 7.62mm pich TLP759 (IGM)

Creepage distance: 7.0mm (min.)

Clearance: 7.0mm (min.)

Insulation thickness: 0.4mm (min.)

Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit	
	Forward current	(Note 2)	I _F	25	mA
	Pulse forward current	(Note 3)	I _{FP}	50	mA
LED	Peak transient forward current	(Note 4)	I _{FPT}	1	Α
	Reverse voltage		V _R	5	V
	Diode power dissipation	(Note 5)	P_{D}	45	mW
	Output current		I _O	8	mA
ō	Peak output current		I _{OP}	16	mA
Detector	Output voltage		Vo	-0.5~20	V
ă	supply voltage		V _{CC}	-0.5~30	V
	Output power dissipation	(Note 6)	PO	100	mW
Оре	erating temperature range	T _{opr}	−55~100	°C	
Stor	rage temperature range	T _{stg}	−55~125	°C	
Lea	d solder temperature(10s)	T _{sol}	260	°C	
Isola	ation voltage(AC,1min.,R.H.≤60%,Ta=25°C)	BVS	5000	V _{rms}	

(Note 2): Derate 0.8mA above 70°C.

(Note 3): 50% duty cycle,1ms pulse width.

Derate 1.6mA / °C above 70°C.

(Note 4): Pulse width PW $\leq 1\mu s$,300pps.

(Note 5): Derate 0.9mW / °C above 70°C.

(Note 6): Derate 2mW / °C above 70°C.

(Note 7): Soldering portion of lead: Up to 2mm from the body of the device.

(Note 8): Device considerd a two terminal device: Pins 1, 2, 3 and 4 shorted together and pins 5, 6, 7 and 8 shorted together.

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Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Тур.	Max.	Unit
LED	Forward voltage	V _F	I _F = 16mA		1.65	1.85	V
	Forward voltage temperature coefficient	ΔV _F / ΔTa	I _F = 16mA	_	-2	_	mV / °C
	Reverse current	I _R	V _R = 5V	_	_	10	μΑ
	Capacitance between terminal	C _T	V _F = 0,f = 1MHz	_	45	_	pF
Detector	High level output current	I _{OH (1)}	$I_F = 0mA, V_{CC} = V_O = 5.5V$	_	3	500	nA
		I _{OH (2)}	I _F = 0mA,V _{CC} = 30V V _O = 20V	_	_	5	μA
		Іон	I _F = 0mA,V _{CC} = 30V V _O = 20V,Ta = 70°C	_	_	50	μΑ
	High level supply voltage	I _{CCH}	I _F = 0mA,V _{CC} = 30V	_	0.01	1	μΑ
	Supply voltage	V _{CC}	I _{CC} = 0.01mA	30	_	_	V
	Output voltage	V _O	I _O = 0.5mA	20	_	_	V

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit	
Current transfer ratio	la / la	I _F = 10mA,V _{CC} = 4.5V V _O = 0.4V	25	35	75	%	
Current transfer ratio	I _O / I _F	I _F = 16mA,V _{CC} = 4.5V V _O = 0.4V,Ta = -25~100°C	15	_	-	/0 I	
Low level output voltage	V _{OL}	I _F = 16mA,V _{CC} = 4.5V I _O = 2.4mA	_	_	0.4	V	

Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	CS	V = 0,f = 1MHz (Note 8)	_	0.8	_	pF
Isolation resistance	R _S	R.H. ≤ 60%,V _S = 500V (Note 8)	1×10 ¹²	10 ¹⁴	ı	Ω
		AC,1 minute	5000	_	-	V_{rms}
Isolation voltage	BV_S	AC,1 second,in oil	_	10000	_	Vdc
		DC,1 minute,in oil	_	10000	_	vuc

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Switching Characteristics (Ta = 25°C,V_{CC} = 15V)

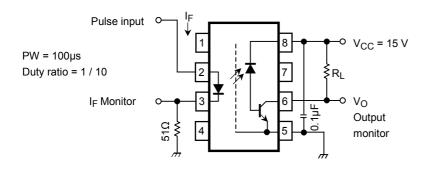
Characteristic		Symbol	Test Cir– cuit	Test Condition	Min.	Тур.	Max.	Unit
Propagation delay time		t _{pHL}	- 1	I_F = 10mA, R_L = 20kΩ	0.1	0.45	0.8	μs
(H→L)		^t pLH		I_F = 10mA,R _L = 20kΩ Ta = 0~85°C	0.1	0.45	0.9	
Propagation delay time (L→H)				I_F = 10mA,R _L = 20kΩ Ta = -25~100°C	0.1	0.45	1.0	
		t _р _н-t _р н_		I_F = 10mA, R_L = 20kΩ	_	0.15	0.7	μѕ
Switching time dispersion between on				I _F = 10mA,R _L = 20kΩ Ta = 0~85°C	_	0.25	0.8	
and off				I_F = 10mA,R _L = 20kΩ Ta = -25~100°C	_	0.25	0.9	
Common mode transient immunity at logic high output	(Note 9)	CM _H	- 2	$I_F = 0mA$ $V_{CM} = 1500V_{p-p}$ $R_L = 20k\Omega$	10000	15000	_	V / μs
Common mode transient immunity at logic low output	(Note 9)	CML		$I_F = 10\text{mA}$ $V_{CM} = 1500V_{p-p}$ $R_L = 20k\Omega$	-10000	-15000	_	V / µs

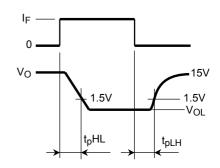
(Note 9): CM_L is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic low state($V_O < 1V$). CM_H is the maximum rate of rise of the common mode voltage that can be

 CM_H is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic high state($V_O < 4V$).

(Note 10): Maximum electrostatic discharge voltage for any pins: 100V(C = 200pF, R = 0).

Test Circuit 1: Switching Time Test Circuit

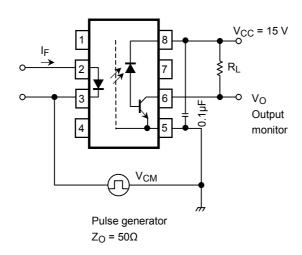


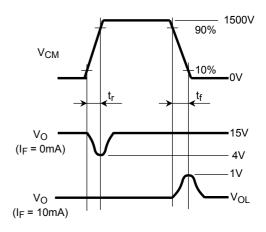


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Test Circuit 2: Common Mode Noise Immunity Test Circuit





$$CM_{H} = \frac{1200(V)}{t_{f}(\mu s)}, CM_{L} = \frac{1200(V)}{t_{f}(\mu s)}$$

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